

Addition of Wide frame assembly line (High Efficiency Production Line) for HTSOP-J8 (LSI)

1st Sep 2021 AP production Headquarters LSI Engineering Div.

Addition of Wide frame assembly line (High Efficiency Production Line) for HTSOP-J8 (LSI)



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1. Background



<Background>

Fortunately, we received many orders for HTSOP-J8. So the production load factor is increasing. We will build a high efficiency line to provide stable production support.

<Purpose>

To increase production capacity and keep stable production support, add HTSOP-J8 high efficiency production line using higher number of products per frame.

Current line's Package name	Accv/ IIna	Test line	Package name After changing		Test line
HTSOP-J8	Semi wide product line (Current	Current	LITCOD 10	Semi wide product line (Current Production line)	Current Test line
111307-30	Production line)	Test line	HTSOP-J8	High efficiency Production line	(No change)

<Changing Schedule>

After getting approval from customers, apply this changing.

2. 4M comparison



Highly efficiency production line's equipment type(Same method) and materials are changed from current production line.

			Semi wide production line (Current production line)	Highly efficiency production line	Changing point	Verification	
Package name		e name	HTSOP-J8	HTSOP-J8	None	No change	
	Dev	rice	Please refer device list	New device name	Yes	Add U or V word	
		Factory	Rohm Philippine (REPI)	Same as current			
		Country	Philippine	Same as current			
Package name HTSOP-J8 HTSOP-J8 No Device Please refer device list New device name Y Factory Please refer device list New device name Y Employee A,000 people Same as current Cannot Please refer below Same as current (Mold) Class 10,000 Same as	None	Factory has not been changed					
Factory	ASSY	mame HTSOP-J8 HTSOP-J8 Non The Please refer device list New device name Please refer device list New device name Please refer device list New device name Peactory Rohm Philippine (REPI) Same as current Country Philippine Same as current Employee 4,000 people Same as current Clean level Please refer below Clean level Please refer below Class 10,000 Same as current (Mold) Class 10,000 Same as current Country Rohm Philippine (REPI) Same as current Country Rohm Philippine (REPI) Same as current Country Philippine Same as current Operator certified as an automotive grade by Rohm Operator certified as an automotive grade by Rohm Die bonding Full auto die bonder machine Same as current Mold press Full auto mold press Same as current Plating Full auto dambar cut machine Same as current Plating Full auto laser marking machine Same as current Handler Full auto laser marking machine Same as current Handler Full auto lead forming machine Same as current Process flow Rohm automotive production line Same as current Process flow Rohm automotive production line Same as current Process flow Rohm automotive production line Same as current Wire bonding Ultra sonic with thermal compression method Same as current Mold press Transfer mold method Same as current Plating Electro plating method Same as current None Socket contact method Same as current	None	ractory has not been changed			
ractory		(DB~WB)	Class 10,000	Same as current			
		(Mold)	Class 10,000	Same as current			
	Toct	Factory	Rohm Philippine (REPI)	Same as current	None	Camo TEST process line	
	rest	Country	Philippine	Same as current	None	Same 1231 process line	
Man	Assy		Operator certified as an automotive grade by Rohm	Same as current	None	Operator has not been	
Man	Test	-	Operator certified as an automotive grade by Rohm	Same as current	None	changed	
		Die bonding	Full auto die bonder machine	Same as current		Machine type of each	
		Wire bonding	Full auto wire bonder machine	Same as current			
	Test Assy	Mold press	Full auto mold press	Same as current			
	Assy	ckage name HTSOP-J8 HTSOP-J8 Device Please refer device list New device name Factory Rohm Philippine (REPI) Same as current Country Philippine Same as current Employee 4,000 people Same as current Clean level Please refer below Same as current (Mold) Class 10,000 Same as current Eactory Rohm Philippine Same as current Clean level Please refer below Same as current (Mold) Class 10,000 Same as current Eactory Rohm Philippine (REPI) Same as current Country Philippine Same as current Tountry Philippine Same as current Departor certified as an automotive grade by Rohm Same as current Tountry Operator certified as an automotive grade by Rohm Same as current Die bonding Full auto die bonder machine Same as current Wire bonding Full auto mide press Same as current Damber cut Full auto dambar cut machine Same as current Damber cut Full auto dambar cut machine Same as current Plating Full auto lead forming machine Same as current Handler Full auto lead forming machine Same as current Ester Full auto lead forming machine Same as current Faster Full auto tester Same as current Process flow Rohm automotive production line Same as current Die bonding Solder bonding/Ag paste dispense method Same as current Mire bonding Uitra sonic with thermal compression method Same as current Plating Full auto taping machine Same as current Die bonding Solder bonding/Ag paste dispense method Same as current Plating Electro plating method Same as current	Yes				
Machino		Plating	Full auto plating machine	Same as current		as current one and	
Масппе		Marking	Full auto laser marking machine	Same as current		full auto. No problem.	
		Lead forming	Full auto lead forming machine	Same as current			
	Toct	Handler	Full auto handler	Same as current			
	1630	Tester	Full auto tester	Same as current	None	Same TEST process line	
	Taping		Full auto taping machine	Same as current			
		Process flow	Rohm automotive production line	Same as current			
		Die bonding	Solder bonding/Ag paste dispense method	Same as current		All more seen in	
Mothod	Test Operator certified as an automotive grade by Rohm Same as current Possible Die bonding Full auto die bonder machine Same as current	Assy	Wire bonding	Ultra sonic with thermal compression method	Same as current	None	
MEUIOU			Same metriou.				
		Plating	Electro plating method	Same as current	Yes None Machine type of e process is differ from current one same method/gr as current one a full auto. No prob None Same TEST proces All process is same method same method Test line isn't cha		
	Test		Socket contact method	Same as current	None	Test line isn't changed	
1aterial			Please refer attachment	Please refer attachment	Yes	Please refer attachment	

2. 4M comparison



<Device name comparison >

Current semi wide production line and Highly efficiently production line will have different device name. The character U or V is added to the device name of Highly efficiently production line.

	Semi wide production line (Current production line)	Highly efficiency production line	Changing point	Verification
Device	BD00FC0EEFJ-ME2	BD00FC0UEFJ-ME2	Yes	Add U or V character

2. 4M comparison



<Material comparison>

Lead frame (strip size only), die attach material, mold resin material is changed.

		Semi wide production line (Current production line)	Highly efficiency production line	Changing point	Verification
	Strip Size	190.8mm x 43 mm	269.5mm x 83mm	Yes	Please check attachment
	Inner design	Depends on device	Same as current	None	
Lead frame	Base metal material	Cu alloy	Cu alloy	None	Only strip size is changed. Base metal material, surface plating, inner design isn't changed
	Surface plating	Ag spot plating	Ag spot plating	None	illilei desigii isii t cilaliged
D: H		Ag paste type A	Ag paste type B	Yes	Please check attachment
Die atti	ach material	Solder type A	Solder type A	None	No change
Wire	e material	Au/Cu	Au/Cu	None	No change
Mold re	esin material	Halogen Free Epoxy resin type A	Halogen Free Epoxy resin type B	Yes	Please check attachment
Outer pla	ating material	100%Sn	100%Sn	None	No change
M	larking	Laser marking	Laser marking	None	Marking words, font type/sizeare no change
Emt	ooss tape	Rohm standard emboss tape	Rohm standard emboss tape	None	No change
Ship	pping reel	Rohm standard reel	Rohm standard reel	None	No change
Packing mat	terial for shipping	Rohm standard cardboard	Rohm standard cardboard	None	No change

3. Package outer & inner comparison



Package outer, marking spec, inner design is no change.

Item	Semi wide production line (Current production line)	Higher efficiency production line
Outer	001A5E 06423	*This picture's marking is different because of dummy sample. Mass production sample is no change
Inner (X-ray)		

4. How to identify semi wide line / high efficiency line products



It is possible to identify current semi wide line products or high efficiency line products by the characters in the 1-pin mark on the product surface.

How to identify current semi wide line products / high efficiency line products

It can be identified by the 1-pin mark on the surface of product.

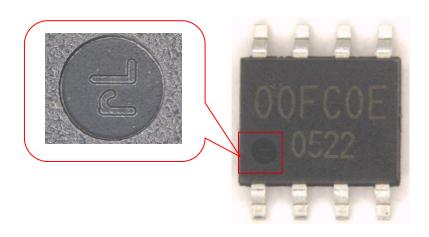
•current line products: 2 characters

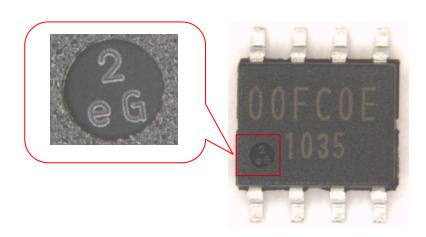
•high efficiency line products: 3 characters

<example (device: BD00FC0EEFJ-ME2) >

<Semi wide production line products (Current) >

< high efficiency line products >

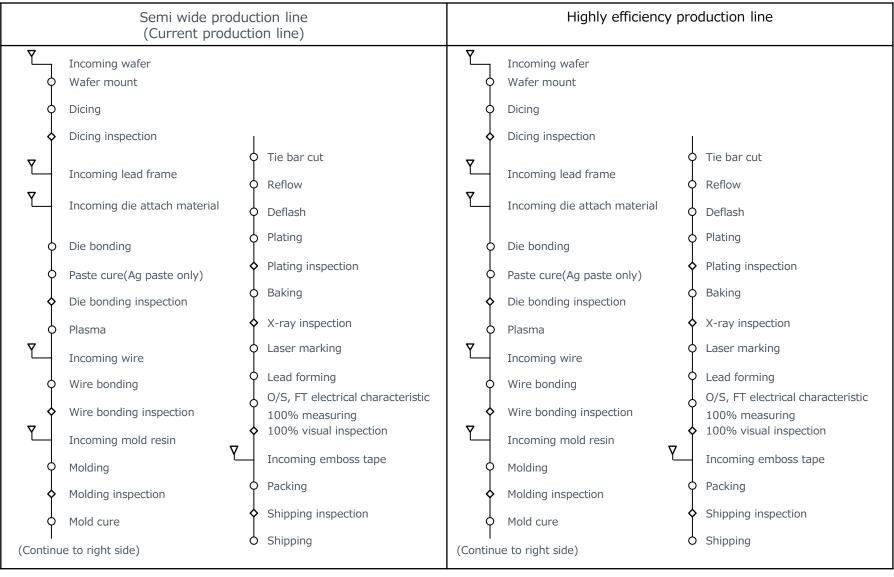




5. Process flow comparison



No change process flow. And test process, shipping spec is also no change.





<Lead frame comparison>

Only lead frame strip size is changed. Inner design and plating spec are no change. Regarding verification results for lead frame strip size change, please refer attachment.

Item Semi wide production line (Current production line)		Highly efficiency production line		
Package	HTSOP-J8	HTSOP-J8		
Factory	Philippine (REPI)	Philippine (REPI)		
Lead frame strip size				
	Strip size: 190.8mm x 43 mm	Strip size: 269.5mm x 83mm		
Lead frame material (Base metal/Surface plating)	Cu alloy / Ag spo plating			
Inner design				



<Die attach material (Ag paste) >

To reduce thermal stress at Reflow process, lower elastic modulus paste has been selected for highly efficiency production line. Regarding verification results for die bonding/wire bonding, please refer attachment.

	Item		Item		Semi wide production line (Current)	Highly efficiency production line	Changing point	Concerned point
Main	material		Ероху	Epoxy/Acryl	res	Degas make lead frame surface Dirty.		
Ag filler conte	ents	%	75.0	76.5	Yes	1 st open because wire bonding force is reduced by soft die attach paste.		
Electrical resist	cance	Ω·cm	σx10 ⁻⁴	5σx10 ⁻³ Ω•cm		Over electrical characteristics spec by electrical conductivity change		
Viscosity		S	19 (2.5rpm)	12 (5rpm)	Yes	 Lead short by paste bridge caused by paste scatter or stringy paste. Thermal shut down by paste/ lead frame delamination caused by thin paste thickness. 		
Tg		Pa∙s	110	28	Yes	•Thermal shut down by paste/ lead frame		
Thermal	a 1	ppm	50	86	1	delamination caused by increasing thermal expand coefficiency. Over electrical characteristics spec		
expand coefficiency	a 2	ppm	95	200	Yes	by thermal stress change.		
Elastic modulus	RT	MPa	11500	2800	Yes	1 st open because wire bonding force is reduced by soft die attach paste.		
Thermal conductivit	У	W/mK	1.5	2.0		Over electrical characteristics spec by thermal conductivity change.		
Chloride ion cor	ntents	ppm	6	<5	Yes	Corrosion risk become low so no problem.		



<Mold resin material>

To reduce reflow stress, low elastic modulus/low water absorption mold resin is selected for highly efficiency production line. Regarding verification results for resin injection in mold process, please refer attachment.

	item		Semi wide production line (Current)	Highly efficiency Production line	Changing point	Concerned point
Main	material		Ероху	Epoxy	None	No change
Fill	er type		Silica	Silica	None	No change
Spiral flo	OW	cm	105	110	Yes	Breakdown by void
Gel time (1	75℃)	S	45	35	Yes	Break down by void or wire open by wire sweep because resin gel time is short.
Tg		$^{\circ}$	130	125	Yes	Thermal shut down by paste/leadframe delamination because increasing a2 resion.
Thermal	a 1	ppm	9.0	9.0	None	No change
Expand coefficiency	a 2	ppm	37	38	Yes	Thermal shut down by paste/ lead frame delamination caused by increasing thermal expand coefficiency.
Bending	RT	MPa	24000	23500		
Elastic Modulus	260℃	MPa	800	600	V	Dia and last FT Farms and in tention
Bending	RT	GPa	180	160	Yes	Die crack by FT Force or pick up in taping
Strength	260℃	GPa	20	16		
Water absorption	Boil	wt%	0.14	0.13	Yes	Reflow stress become lower. No problem
Electrical cond	ductivity	μS/cm	<80	<150	Yes	Over electrical characteristics spec by Electrical conductivity change.
Chloride ion c	contents	ppm	<30	<20	Yes	Corrosion risk become low so no problem.



<Lead frame change>

Based on DRBFM and process evaluation item, the result is no problem. For details, please refer attachment.

Changing point	Concerned point	Evaluation item	Pn/N	Results	Judgment	Page
	1 st /2 nd open by weak lead frame clamp at wire bonding process.	·Wire bonding process margin evaluation	0/30 wires	1 st ball/2 nd bonding is No problem in production Margin.	Pass	p.16
	Easy to deform lead frame, and caused solder mount NG by leak mold resin to heatsink	•Outer dimension measurement	0/10 pcs	Cpk>1.67 and no problem	Pass	p.20
Strip size change 190.8mm x 43 mm →269.5mm x 83mm	Sn plating thickness become over spec	·Sn plating thickness measurement	0/60 leads	Cpk>1.67 and no problem	Pass	p.19
	Void is occurred because mold injection time is longer and resin become harder.	•Mold margin evaluation	-	No void in production margin	Pass	p.17
	Wire sweep is occurred because mold injection time is longer and resin become harder.	•Mold margin evaluation	-	No wire sweep in production margin	Pass	p.17

7. Verification of changing points



<Die attach material change>

Based on DRBFM and process evaluation item, the result is no problem. For details, please refer attachment.

Changing point	Concerned point	Evaluation item	Pn/N	Results	Judgment	Page
Ероху	Degas make lead frame surface dirty, and paste/lead frame Delamination is occurred.	•MSL	0/24pcs	No delamination	Pass	p.25
→Epoxy/Acryl change	Degas make lead frame surface dirty, and caused wire open	•MSL	0/24pcs	No delamination	Pass	p.25
Elastic modulus lower 11500→2800MPa	1^{st} open because wire bonding force is reduced by soft die attach paste.	·Wire bonding margin evaluation (1 st ball shear strength check)	0/30 wires	1 st ball shear strength is no problem in production margin	Pass	p.16
Increase electrical resistance $\sigma x 10^{-4} \Omega \cdot cm$ $\rightarrow 5 \sigma x 10^{-3} \Omega \cdot cm$	Over electrical characteristics spec by electrical conductivity change	•Electrical characteristic measurement	0/100 (Representative device)	representative device. Objected	Pass	p.22
Tg lower (-82℃) /Increase thermal	Thermal shut down by paste/ lead frame delamination caused by increasing thermal expand coefficiency.	•MSL	0/24pcs	No delamination	Pass	p.25
expand coefficiency (a1:72%, a2:111% up)	Over electrical characteristics spec by thermal stress change.	•Electrical characteristic measurement		in production margin Cpk>1.67 measured by representative device. Objected Device will be measured by evaluation lot. No delamination Cpk>1.67 measured by evaluation lot. Cpk>1.67 measured by representative device. Objected Device will be measured by evaluation lot. According to representative device, thermal resistance of higher efficient production line is 2.8°C/W higher than current one. Objected device will be measured by evaluation lot.	Pass	p.22
Increase thermal conductivity	Over thermal characteristics Spec by thermal conductivity change	•Thermal resistance Measurement comparison (Current production line vs highly efficient production line)	-	thermal resistance of higher efficient production line is 2.8℃/W higher than current one. Objected	Pass	p.24
Viscosity change	Lead short by paste bridge caused by paste scatter or stringy paste.	•Die bonding margin evaluation		No paste scatter or stringy paste in production margin	Pass	p.15
viscosity change	Thermal shut down by paste/ lead frame delamination caused by thin paste thickness	•MSL	0/24pcs	No delamination	Pass	p.25

7. Verification of changing points



<Mold resin change>

Based on DRBFM and process evaluation item, the result is no problem. For details, please refer attachment.

Changing point	Concerned point	Evaluation item	Pn/N	Results	Judgment	Page
Increase thermal expand	Thermal shut down by paste/ lead frame delamination caused by increasing thermal expand coefficiency.	•MSL	0/24pcs	No delamination	Pass	p.25
coefficiency a2: 2.7% up	Over electrical characteristics spec by electrical conductivity change	•Electrical characteristic Measurement	0/100 (Representative device)	Cpk>1.67 measured by representative device. Objected device will be measured by evaluation lot.	Pass	p.22
Spiral flow 4.8% longer	Breakdown by void	•Mold margin evaluation	-	No void in production margin	Pass	p.17
Gel time 29% shorter	Break down by void or wire open by wire sweep because resin gel time is short.	•Mold margin evaluation	-	No void/wire sweep NG in production margin	Pass	p.17
Lower Tg t→ t-5℃	Thermal shut down by paste/lead frame delamination because increasing a2 region.	•MSL	0/24pcs	No delamination	Pass	p.25
Lower bending elastic modulus 25℃: 2.1% down 260℃:33.3% down	Die crack by FT Force or pick up in taping	•SAT evaluation On chip	0/24pcs	No die cracks	Pass	p.21
Lower water absorption 7.7% down	Thermal shut down by paste/ lead frame delamination caused by water distribution in product.	•MSL	0/24pcs	No delamination	Pass	p.25
Higher electrical conductivity	Over electrical characteristics spec by Electrical conductivity change.	•Electrical characteristic Measurement	(Representative	Cpk>1.67 measured by representative device. Objected device will be measured by evaluation lot.	Pass	p.22



<Die bonding evaluation>

To verify paste viscosity change, conduct Die bonding margin evaluation. Paste spread·height is no problem and no stringy paste/paste scattering is occurred. There is no problem.

(Evaluation contents)

Package: HTSOP-J8 (High efficiency production line)

Device: Dummy chip (Chip size: 2.7x2.1x0.3tmm [MAX chip size])

(Judgment standard)

•Paste spread: ≥ 60% of chip side

•Paste height: (Chip size t√Paste height x)

A mode: x<1/2t, B mode:1/2t<x<2/3t, C mode:2/3t<x

[Evaluation condition]

	Dispense pressure (MPa)								
-100 -50 Center +50 +100 +150									
1	2	3	4	5	6				

Production control

Condition	1	2	3	4	5	6
Paste appearance	Can't dispense C mode	A mode				
Paste Spread		A mode				
Paste height (Chip X)		A mode				
Paste height (Chip Y)		A mode	A mode	A mode	B mode	C mode



<Wire bonding 1stbonding evaluation>

To verify lower elastic modulus paste, conduct 1stbonding margin evaluation. Ball shear strength·ball appearance are no problem and No under PAD is occurred.

(Evaluation contents)

Package : HTSOP-J8 (High efficiency production line) Wire: $Au\phi 30um$ Evaluation Qty : N=30 balls

[Judgment standard]

·Ball appearance: No decentering or smash ball

·Ball size/thickness:75±5um/15±5um

·Ball shear strength: ≥200 mN and exist Au residue or Al slide trace

No under pad crack

[Evaluation condition]

		USG Current (mA)								
		-20	-10	Center	+10	+20				
	+5	6				7				
	-5		2		3					
Force	Center			1						
	+5		5		4					
	+10	9				8				

Production control

	Condi	ion	1	2	3	4	5	6	7	8	9
۵)	Size	Х	75.3	73.7	74.7	77.0	74.7	73.3	77.7	81.7	74.0
ance	Size	У	76.0	73.3	75.7	77.3	75.0	73.3	77.7	81.0	75.0
appearance	Thicknes	s t	18.0	20.7	17.3	15.7	18.3	20.7	15.7	13.0	19.7
Ball app	Appea	arance									
	yth)	Average	452.8	468.5	457.0	460.0	448.3	447.9	448.5	472.8	444.1
ar	Strength (mN)	Max	460.7	501.5	485.1	488.9	463.6	469.4	488.6	510.4	470.2
l shear	St	Min	438.8	421.4	424.5	431.8	428.8	427.7	77.7	416.5	402.1
Ball	Мс	ode									
Under pad	Appea	arance									
U	Pn	/N	0/30	0/30	0/30	0/30	0/30	0/30	0/30	0/30	0/30
	Judgm	ent	OK	NG	OK						



<Wire bonding 2nd bonding evaluation>

To verify lead frame strip size changing effect, conduct 2ndbonding margin evaluation. Pull strength•peel test are no problem.

[Evaluation contents]

Package: HTSOP-J8 (High efficiency production line) Wire: Auφ30um Evaluation Qty: N=30 wires

(Judgment standard)

Appearance : No peeled offPeel test : Exist crescent residue

•Pull strength : ≥40 mN

[Evaluation condition]

		USG Current (mA)									
		-20	-10	+10	+20						
	+5	6				7					
	-5		2		3		I				
Force	Center			1			1				
	+5		5		4		1				
	+10	9				8					

Production control

(Condition	1 2 3		4	5	6	7	8	9	
A	opearance	100	10	10	S	10	6		1	10
	Peel test	6	0	6	6	6		6	0	0
(mN)	Average	122.6	123.5	120.7	123.2	121.5	126.0	123.1	120.1	120.7
strength(mN)	Max	133.6	150.8	143.5	142.5	133.3	141.6	146.4	147	134.1
Pull st	Min	112.0	107.9	104.3	103.9	111.1	111.4	104.6	105.2	106.1
J	udgment	OK	ОК							



<Mold evaluation>

To verify lead frame strip size and short gel time/spiral flow mold resin, conduct injection speed/pressure margin evaluation. Wire sweep/void are no problem.

(Evaluation contents)

Package: HTSOP-J8 (High efficiency production line) Wire: Auφ25um

Evaluation Qty: N=576pcs

(Judgment standard)

- ·Wire sweep ≤10%
- ·Void≦0.5mm

Production control

Production control

				fer speed / mi		
		0.10	0.25	0.50	0.75	1.00
	15.0	9.5%				7.1%
		9.5%				7.1%
	17.5					
			5.0%		5.9%	
Prunger Pressure / kN	19.7					
				7.0%		
	22.5					
			8.6%		6.2%	
	25.0	13.7%				8.1%

			2nd Tra	nsfer speed /	mm/sec	
		0.10	0.25	0.50	0.75	1.00
	15.0					0
	17.5					
Prunger Pressure / kN	19.7			10		
	22.5					
	25.0					



<Sn plating thickness measurement>

To verify lead frame strip size, conduct Sn plating thickness measurement. Sn plating thickness is Cpk > 1.67 and no problem.

(Evaluation contents)

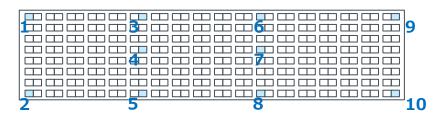
Package: HTSOP-J8 (High efficiency production line) Evaluation Qty: 60 leads (10 pcs×6 leads/pc)

[Judgment standard]

Plating thickness: 8~20 um

[Sampling point]

Please refer sampling location below.



[Result] (Unit: um)

	Sampling point											Cnk
	1	2	3	4	5	6	7	8	9	10	Total	Cpk
Average	12.1	12.1	11.5	11.9	10.9	11.9	12.1	11.0	12.0	12.0	11.8	
Max	12.7	13.1	12.3	12.2	11.7	12.7	12.9	12.2	12.9	12.9	13.1	1.72
Min	11.0	10.5	10.7	11.4	10.2	11.1	11.4	10.1	11.5	11.0	10.1	1./2
σ	0.70	0.97	0.57	0.33	0.55	0.71	0.49	0.72	0.50	0.60	0.73	



<Solder wettability evaluation>

Zero cross time was under 3.0s, so there is no problem with the solder wettability.

(Evaluation contents)

Package: HTSOP-J8 (High efficiency production line)

Method: Meniscograph method

(Solder Bath:Sn-3Ag-0.5Cu、245℃)

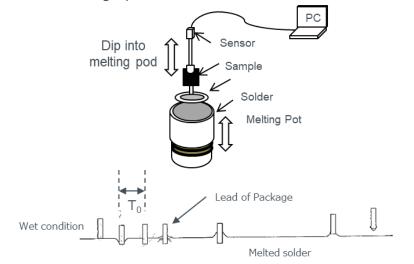
Qty: 5 pcs

【Judgement standard】

Zero cross time(T0)≤3s (EIAJ ED-4701/303)

[Solder wettability test]

Use Meniscograph method and measure zero cross time.



(Evaluation result)

(unit:s)

	1	2	3	4	5	Ave.	Max.	Min.	Judgem ent
Zero cross time T0 [s]	2.0	2.0	1.9	2.1	2.3	2.1	2.3	1.9	PASS



<Outer dimension measurement>

To verify lead frame strip size, conduct outer dimension measurement. Cpk > 1.67 and no problem.

(Evaluation contents)

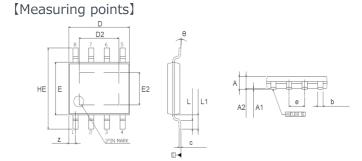
Package: HTSOP-J8

Evaluation Qty: 10 pcs

[Judgment standard]

Cpk≥1.67 for each dimension

<Current production line>



	А	A1	A2	D	D2	HE	E	E2	b	С	е	L	L1	Z	θ
	1.0 Max.	0.08±0.08	0.85±0.05	4.9±0.1	(3.2)	6.0±0.2	3.9±0.1	(2.4)	0.42 +0.05/-0.04	0.17 +0.05/-0.03	1.27	0.65±0.15	1.05±0.2	0.545	4°+6°/-4°
Ave.	0.98	0.12	0.86	4.95	3.11	6.00	3.89	2.33	0.41	0.17	1.27	0.59	1.07	0.56	3.28
Max.	0.98	0.13	0.86	5.04	3.14	6.02	3.90	2.37	0.42	0.17	1.28	0.61	1.12	0.58	3.56
Min.	0.97	0.11	0.84	4.87	3.08	5.98	3.87	2.25	0.40	0.16	1.26	0.58	1.05	0.52	3.08
σ	0.00	0.01	0.01	0.06	0.02	0.01	0.01	0.03	0.01	0.01	0.00	0.01	0.02	0.02	0.15
Cpk	1.80	2.20	2.16	1.80	-	7.22	2.77	-	1.97	1.69	-	3.82	2.95	-	7.12

<High efficiency production line>

vi ligii k	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	ichey production inter													
	Α	A1	A2	D	D2	HE	E	E2	b	С	е	L	L1	Z	θ
	1.0 Max.	0.08±0.08	0.85±0.05	4.9±0.1	(3.2)	6.0±0.2	3.9±0.1	(2.4)	0.42 +0.05/-0.04	0.17 +0.05/-0.03	1.27	0.65±0.15	1.05±0.2	0.545	4°+6°/-4°
Ave.	0.95	0.13	0.85	5.03	3.17	6.02	3.87	2.39	0.41	0.16	1.27	0.66	1.08	0.61	3.50
Max.	0.96	0.14	0.86	5.07	3.22	6.04	3.88	2.41	0.42	0.17	1.28	0.69	1.11	0.66	4.06
Min.	0.93	0.12	0.84	5.00	3.15	6.00	3.85	2.36	0.41	0.16	1.26	0.64	1.06	0.55	2.93
σ	0.01	0.01	0.01	0.02	0.02	0.01	0.01	0.01	0.00	0.00	0.00	0.02	0.02	0.03	0.40
Cpk	1.82	2.09	2.22	3.24	-	5.14	2.47	-	2.98	1.75		2.37	3.10	-	2.90

(unit: mm)

(unit: mm)



<SAT evaluation on chip surface>

As a result of the SAT evaluation on chip surface, we have confirmed that there is no problem with the low elasticity of the mold resin.

(Judgement standard)

·appearance : No pellet crack

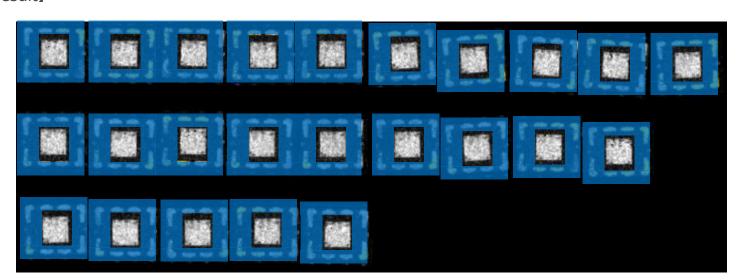
[Judgement contents]

Package : current semi wide line/high efficiency line

Device : representative model

Qty: N=24pcs

SAT result





<Electrical characteristic measurement>

To verify mold/die attach paste change, conduct important electrical characteristic measurement (Output voltage) by representative device. Cpk > 1.67 and no problem.

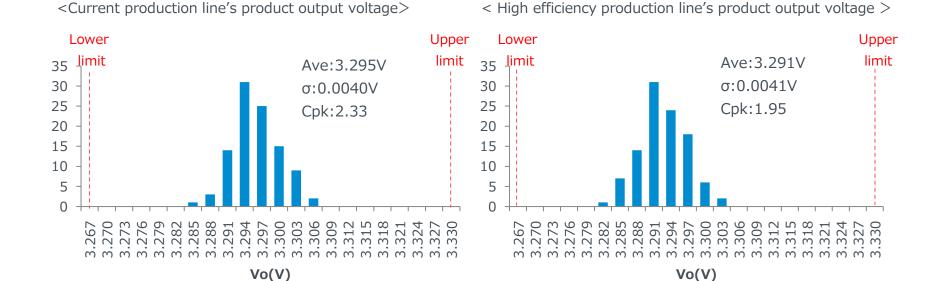
(Evaluation contents)

Package : HTSOP-J8

Device: BD33FC0EEFJ-M

Judgment standard : 3.3+/-1 % V, and Cpk ≥1.67

Measurement Qty : N=100pcs





<Thermal resistance measurement>

To verify die attach paste change, compare current production line's product with highly efficiency production line's one about thermal resistance by representative device. Thermal resistance of highly efficiency production line's product is about 2.8°C/W higher than current production line's one. Objected devices will be measured by evaluation lot.

(Measuring condition)

Package : HTSOP-J8 St.

Device : BD50HA3EEFJ

Measuring machine : T3Ster (MentorGraphics)

Environment : JESD51-2A

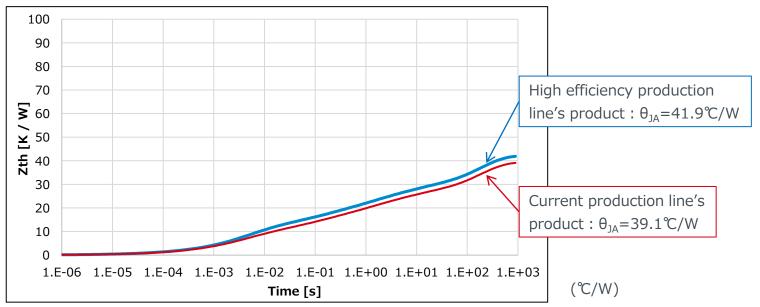
Substrate : Rohm 4 layers substrate

(Result)

Substrate information Rohm 4 layers substrate

> : FR4(Glass epoxy) substrate 114.3mm×76.2mm×1.6mmt

1st layer: Cupper foil, land pattern+wiring for measuring 2nd、3rd、backside layer: Cupper foil, 74.2mm×74.2mm





<MSL>

To verify mold/die attach paste change, conduct MSL test by following JEDEC. No delamination is found and no problem.

(Evaluation contents)

Package: HTSOP-J8 (High efficiency production line)

Device: BD4271EFJ-C Evaluation Qty: N=24pcs

[Pre-condition]

MSL	JEDEC LEVEL 1
Drying	<u>125℃ 24h</u>
Moisture	<u>85℃ 85% 168h</u>
Reflow	Pb free profile (260°C) 3 times

[Judgment standard] IPC/JEDEC J-STD-020E

	Judgment standard/ Evidence of judgment standard	JEDEC Table No.
Chip (surface)	No delamination /To avoid wire open	6.2.1.1a
Island (Surface)	No delamination at down bonding area/To avoid wire open **Objected devices are not applicable because of no down bonding.	6.2.1.1b
Paste/Island Interface	Delamination area < 50% in initial condition and no change after MSL. ("High heat radiation" or "Ohmic contact at chip backside" device is applicable) /To avoid heat radiation grade down or non-ohmic contact.	6.2.1.1d
Inner lead (Surface)	Delamination area < 100%. If 100% delamination is found, conduct quality assurance Test and judge by electrical characteristic/To avoid wire open	6.2.1.1e

[Result]

Measuring point	Chip (Surface)	Island (Surface)	Paste/Island Interface	Judgment
Pn/N	0/24	0/24	0/24	Pass



We conducted reliability test based on JEDEC. There is no problem.

(Evaluation contents)

Package: HTSOP-J8 (High efficiency production line)

Device : BD4271EFJ-C Evaluation Qty : N=24pcs

(Judgment standard)

IPC/JEDEC J-STD-020E

[Result]

Chip (surface)	Paste-Island interface	Inner lead (surface)
0/24	0/24	0/24



Compared current production line and high efficiency production line, each process is equivalent.

■ Evaluation device information

•Device name : BD00FC0EEFJ-ME2

·Chip size: 1.81x1.91x0.30tmm

·Wire: Au28 um (the wire layout is shown on the right)





Pn: the number of defects

				Evaluation res	ult (Pn/n)		
Process	Check item	Judgement standard	Qty	Semi wide production line (Current)	High efficiency line	Judgement	item
	Paste spread/scatter	≧60%/side, No scatter	288 pcs	0/288pcs	0/288pcs	Pass	
Die bonding	Paste height	≦two-thirds of die height	288 pcs	0/288pcs	0/288pcs	Pass	P.28
	Hajiki test	≧80% Si chip residue	30pcs	0/30pcs	0/30pcs	Pass	
	Ball size	Within ROHM standard (X, Y: 60±10um Z: 14±5um)	30 wire	0/30 wire	0/30 wire	Pass	
Wire bonding	Ball shear test	Strength:≥300mN exist Au residue or Al slide trace	30 wire	Cpk=1.81	Cpk=1.85	Pass	P.29
Wire boriding	appearance/ no crack under PAD	No decentering or smash ball /no crack under PAD	30 wire	0/30 wire	0/30 wire	Pass	
	2 nd pull strength	≥0.06N	30 wire	Cpk=1.70	Cpk=1.72	Pass	P.30
	2 nd appearance/peel test	No peeled off and exist crescent residue	30 wire	0/30 wire	0/30 wire	Pass	P.30
Mold	Wire sweep	≦ 10%	15pcs	Cpk=2.14	Cpk=3.30	Pass	P.31
Mold	Inner void	Void ≤ 0.5mm	288pcs	0/288pcs	0/288pcs	Pass	P.31
Diating	Plating thickness	8~20 um	60 lead	Cpk=1.73	Cpk=1.78	Pass	P.32
Plating	Solder wettability test	Zero cross time ≤ 0.3s	5pcs	0/5pcs	0/5pcs	Pass	P.32
Lead forming	Appearance	Based on visual inspection criteria	100pcs	0/100pcs	0/100pcs	Pass	P.33



<DB process>

The results show that appearance and bonding strength are equivalent.

			result	
Check item	Judgement standard	Semi wide production line (Curent)	High efficiency production line	judgement
Paste spread/scatter	≧60%/side, No scatter	Pn/N = 0/288 pcs	Pn/N = 0/288 pcs	Pass
Paste height	≤two-thirds of die height	Pn/N = 0/288 pcs	Pn/N = 0/288 pcs	Pass
Hajiki test	≥80% Si chip residue	Pn/N = 0/30 pcs	Pn/N = 0/30 pcs	Pass



 $\langle WB \text{ process } (1) \rangle$

The results show that ball size and ball shear strength are equivalent.

						r	es	ult						
Check item	Judgement standard	S	Semi wide production line (Current)		High efficiency production line				Judgement					
				X	Υ	Z				X	Υ	Z		
			Ave	62.1	62.4	14.0			Ave	61.8	61.4	15.1		
	.V V: 60±10um		MAX	65.0	65.1	15.8			MAX	63.6	63.5	16.1		
Ball size	•X, Y: 60±10um •Z: 14±5um		MIN	59.0	60.0	12.8			MIN	59.8	59.1	14.2		pass
			σ	1.1	1.1	0.92			σ	1.1	1.1	0.7		
			Cpk	2.39	2.30	1.81			Cpk	2.48	2.60	1.85		
			Pn/	'N = 0/	30 wire	e [um	1]		Pn,	/N = 0	/30 wir	e [ur	n]	
			S	trength [N]		hear node				Strengt [N]		Shear mode		
	Strength:≥300mN	A	Ave	0.43				A	Ave	0.42	1			
Ball shear test	exist Au residue	M	1AX	0.49				M	1AX	0.48		1		pass
	or Al slide trace	N	1IN	0.38				N	/IN	0.38				,
			σ	0.02	Ev	ist Au			σ	0.02		Exist Au		
			Cpk	1.81		sidue			Cpk	1.85		esidue		
M.Co. Ltd			Pn/	'N = 0/	30 wire	е			Pn	/N = 0	/30 wir	e		



<WB process (2)>

The results show that no crack under PADs and wire appearance/pull strength are equivalent.

		resi	ult	
Check item	Judgement standard	Semi wide production line (Current)	High efficiency production line	Judgement
Appearance no crack under PAD	No decentering or smash ball /no crack under PAD	No decentering/smash No crack under PAD $Pn/N = 0/30$ wire	No decentering/smash No crack under PAD $Pn/N = 0/30$ wire	Pass
2 nd pull strength	≥0.06N	strength[N] Ave 0.13 Max 0.14 Min 0.09 σ 0.013 Cpk 1.70 Pn/N = 0/30 wire	strength[N] Ave 0.09 Max 0.10 Min 0.08 σ 0.010 Cpk 1.72 Pn/N = 0/30 wire	Pass
2 nd appearance peel test	No peeled off and exist crescent residue	No peeled off exist crescent residue Pn/N = 0/30 wire	Peel test No peeled off exist crescent residue Pn/N = 0/30 wire	Pass



<Mold process >

The results show that MOLD process is equivalent.

		res	sult	
Check item	Judgement standard	Semi wide production line (Current)	High efficiency production line	Judgement
Wire sweep	≦ 10%	Ave 2.00 Max 4.70 Min 0.50 σ 1.2 Cpk 2.14 [%] Pn/N = 0/15 pcs	Ave 1.93 Max 3.20 Min 0.30 σ 0.81 Cpk 3.30 [%] Pn/N = 0/15 pcs	Pass
Inner void	Void ≦ 0.5mm	No inner void $Pn/N = 0/288 \text{ pcs}$	No inner void Pn/N = 0/288 pcs	Pass



<Plating process>

The results show that plating thickness and solder wettability are equivalent.

		res	sult	
Check item	Judgement standard	Semi wide production line (Current)	High efficiency production line	Judgement
Plating thickness	8~20 um	Ave 13.2 Max 15.19 Min 11.36 σ 1.0 Cpk 1.73 [um] Pn/N = 0/60 lead	Ave 11.04 Max 12.18 Min 10.07 σ 0.57 Cpk 1.78 [um] Pn/N = 0/60 lead	Pass
Solder wettability test	Zero cross time ≤ 0.3s (EIAJ ED-4701/303)	No. Zero cross time 1	No. Zero cross time 1 2.21 2 1.85 3 2.26 4 1.70 5 1.86 Ave 1.98 Max 2.26 Min 1.70 Pn/N = 0/5 pcs [s]	Pass



<Lead forming process>

The results show that product appearance is equivalent.

		res	sult	
Check item	Judgement standard	Semi wide production line (Current)	High efficiency production line	Judgement
Appearance	Appearance criteria (crack, marking identification, no lead deformation)	Top Back side Side No appearance defects (Pn/N = 0/100 pcs)	Top Back side Side No appearance defects (Pn/N = 0/100 pcs)	Pass

10. Comparison of characteristics



<Selecting Device for Electrical and heat radiation characteristic evaluation >

The following device are selected in consideration of their electrical and heat radiation characteristics.

1. Electrical characteristic

Due to change mold materials, check if the stress change on the chip affects the electrical characteristics.

[Key factors]

- > Device with high stress on the chip
- →Large chip size
- > Device with high sensitivity to stress
- →LDO regulator device



2. Heat radiation characteristic

Check the impact of changes in Ag-paste on the heat radiation characteristic

[key factors]

- ➤ Chip size
 - →Max/Min size device are selected
- > Device with high sensitivity heat generation
 - ightarrow LDO and swithing regulator device

Representative device > BD00FC0EEFJ-ME2
BD33IA5EEFJ-ME2
BD90620EFJ-CE2

10. Comparison of characteristics



<Stress simulation analysis for the relationship between chip size and the stress>

As a result of this simulation, the stress on the chip due to the mold resin change decreased for each chip size, so the effect on the electrical characteristics considered to be small.

(Simulation contents)

Package: current line/high efficiency line

Device: see figure at right

analysis soft : midasNFX (linear model)

analysis condition: 175°C→25°C

Application	LDO re	gulator	Switching regulator
Device	BD33IA5EEFJ-ME2	BD00FC0EEFJ-ME2	BD90620EFJ-CE2
Chipsize	0.80mm x 0.75mm	1.81mm x 1.91mm	2.80mm x 2.00mm
Simulation model (1/4model)	Chip Mold resin Leadframe		

Device name	BD33IA5EEFJ-ME2	BD00FC0EEFJ-M	BD90620EFJ-CE2
Chip size	0.80mm x 0.75mm	1.81mm x 1.91mm	2.80mm x 2.00mm
High efficiency production line	Max stress Max stress: 263.3MPa	Max stress Max stress:328.7MPa	Lead frame Mold resin Max stress Max stress: 344.1MPa
Semi wide production line (Current)	Max stress Max stress:282.2MPa	Max stress Max stress:342.2MPa	Max stress Max stress 357.7MPa
Stress reduction rate	▲6.7%	▲3.9%	▲3.6%

MIGAS
SOLID STRS
VON MISES, N/mm²
178, +3 5e+002
178, +3 3e+002
178, +3 3e+002
178, +3 2e+002
198, +3 1e+002
7.48, +3 1e+002
7.49, +3 1e+002
1428, +2 3e+002
19.28, +2 5e+002
19.78, +2 5e+002
10.78, +2 5e+002

The larger the chip size, the more stress on the chip.

High efficiency line products reduce the stress on the chip due to the difference in hardness of the mold resin.

10. Comparison of characteristics



< Electrical characteristics of BD00FC0EEFJ-ME2>

For following device, all of the important factors of electrical characteristics are satisfied Cpk> 1.67. The results show that current/high efficiency line products are equivalent

■ Evaluation condition

Device : BD00FC0EEFJ-ME2 (LDO regulator)

•Qty : Current production line :N=278 pcs, high efficiency production line : N=5697 pcs

	spec			result				
Measurement items				σ		Cpk		Judgement
	Min	Тур.	Max	Current line	High efficiency line	Current line	High efficiency line	
Shutdown current [uA]	-	0	5	0.019	0.011	6.02	14.24	Pass
Bias current [mA]	-	0.5	2.5	0.0084	0.0094	6.32	6.51	Pass
Output voltage (VCC=4V)[V]	Vo×0.99	Vo	Vo×1.01	0.0050	0.0043	3.43	4.22	Pass
Output voltage (VCC=36V)[V]	Vo×0.99	Vo	Vo×1.01	0.0050	0.0047	4.35	4.59	Pass
Input/output voltage difference[mV]	-	300	500	0.0046	0.0032	2.91	5.30	Pass
Input stability [mV]	-	20	80	0.8	0.9	4.61	3.90	Pass
Output stability[mV]	-	30	60	1.8	1.8	2.22	3.21	Pass
EN bias current[uA]	-	25	50	0.36	0.40	3.83	3.63	Pass

10. Comparison of characteristics



< Comparison of thermal resistance>

Compare current production line with high efficiency production line by 3 different chip size devices about thermal resistance. High efficiency production line's sample is max $2.5^{\circ}C/W$ higher than current production line. Please cooperate to judge this effect for customer's application.

[Measuring condition]

Package: HTSOP-J8 current semi wide production line with high efficiency

production line

Device : Please refer below

Measuring tool: T3Ster(MentorGraphics)

Standard: JESD51-2A

Board: Rohm 4-layers board

Substrate's information

Rohm 4-layers substrate: FR4(Glass epoxy) board

114.3mm×76.2mm×1.6mmt

Surface cupper layer land pattern+wiring for measure

2nd /3rd /Backside cupper layer 74.2mm×74.2mm

Device	Chip size	Difference of thermal resistance (current production line with high efficiency production line)
BD33IA5EEFJ-ME2	0.80mm × 0.75mm	∆2.0℃/W
BD00FC0EEFJ-ME2	1.81mm × 1.91mm	∆2.1℃/W
BD90620EFJ-CE2	2.80mm × 2.00mm	∆2.2℃/W

Measurement variation is ≤10%, Max 2.5°C/W.



We conducted reliability test based on AEC-Q100. There is no problem.

<Sample>

Package: HTSOP-J8 (High efficiency production line)

Device: BD4271EFJ-C

Pre-condition: MSL1 (125 $^{\circ}$ C/24h \Rightarrow 85 $^{\circ}$ C/85% 168h \Rightarrow Reflow 260 $^{\circ}$ C peak (3 times))

<Result>

Item	Condition	Result	Analysis of good sample	Analysis item
TC	-65℃⇔150℃ 500cyc	0/22	0/2	Passivation crack, Wire crack
PCT	121℃ 100% 2atm 192h	0/22	0/2	Al PAD corrosion
HAST	130℃ 85% w/bias 192h	0/22	0/2	Al PAD corrosion
HST	150℃ 2000h	0/22	0/2	Wire open by kirkendal void



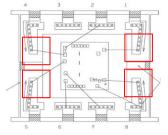
<TC 500cyc Analysis of good sample (1)>

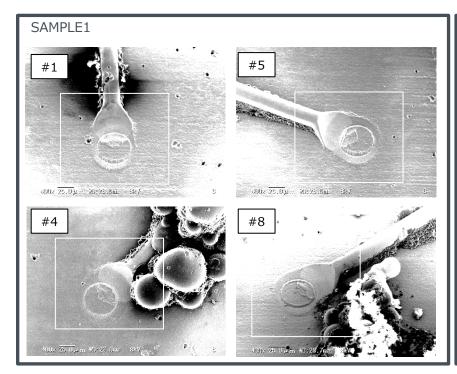
TC 500cyc, there are no crack at 2nd bond. There is no problem.

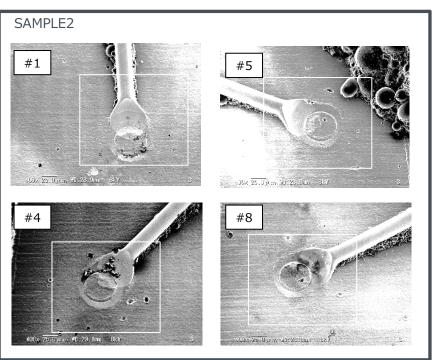
■ Judgment standard: No crack at 2nd bond position

■ Number of samples : N=2pcs

■ Method : Mold opening \Rightarrow SEM (×400)









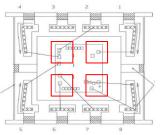
<TC 500cyc Analysis of good sample (2)>

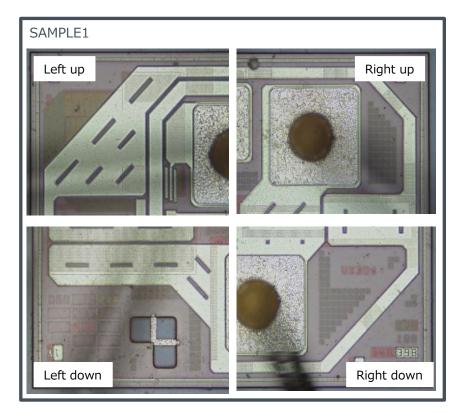
TC 500cyc, there are no passivation crack. There is no problem.

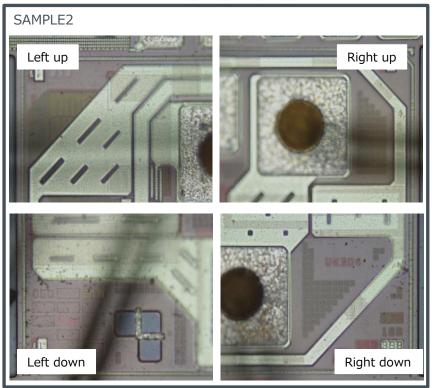
■ Judgment standard : No passivation crack

■ Number of samples : N=2pcs

■ Method : Mold opening \Rightarrow Microscope (×200)









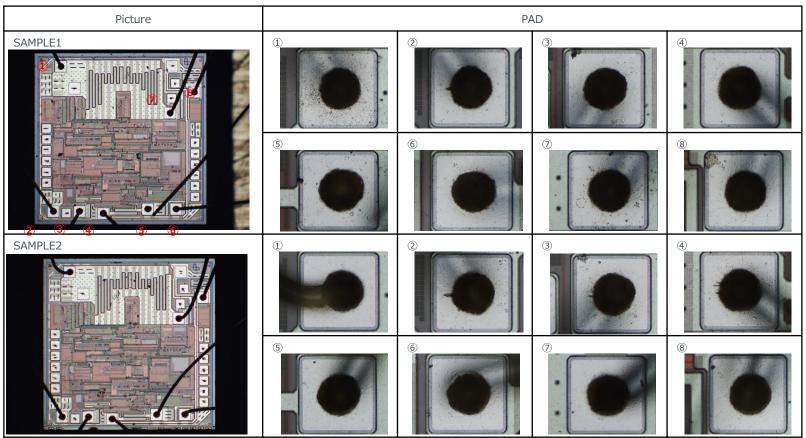
<PCT 192h Analysis of good sample (1)>

PCT192h, thare are no PAD corrosion. There is no problem.

■ Judgment standard : No PAD corrosion

■ Number of samples : N=2pcs

■ Method : Mold opening \Rightarrow Microscope (×200)





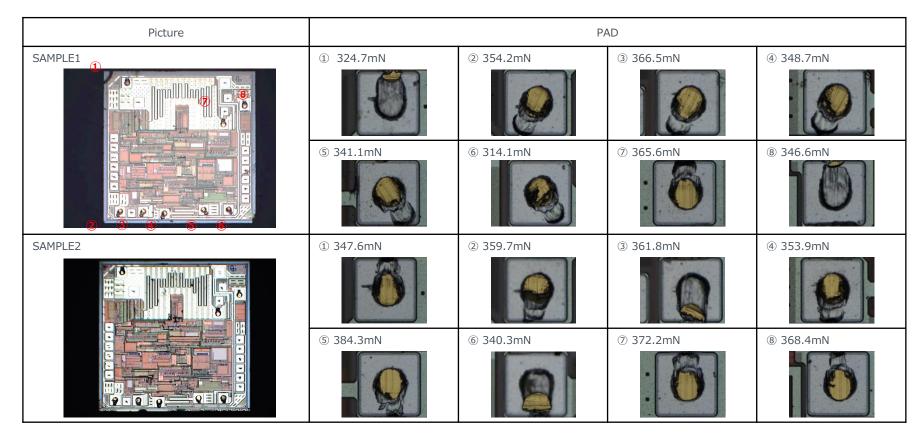
<PCT 192 h Analysis of good sample (2)>

PCT192h, WB share test is no problem.

■ Judgment standard : Above 200mN (Share strength), with Au remain or Al slide.

■ Number of samples : N=2pcs

■ Method : Mold opening \Rightarrow Microscope (×200)





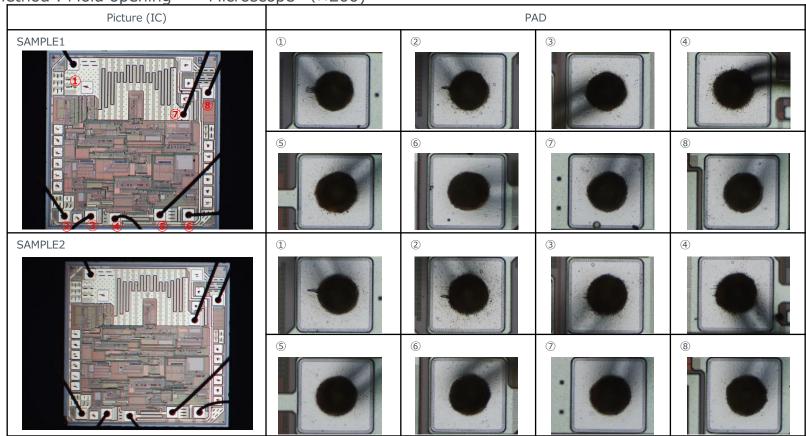
<HAST 192 h Analysis of good sample (1)>

HAST192h, there are no PAD corrosion. There is no problem.

■ Judgment standard : No PAD corrosion

■ Number of samples : N=2pcs

■ Method : Mold opening \Rightarrow Microscope (\times 200)





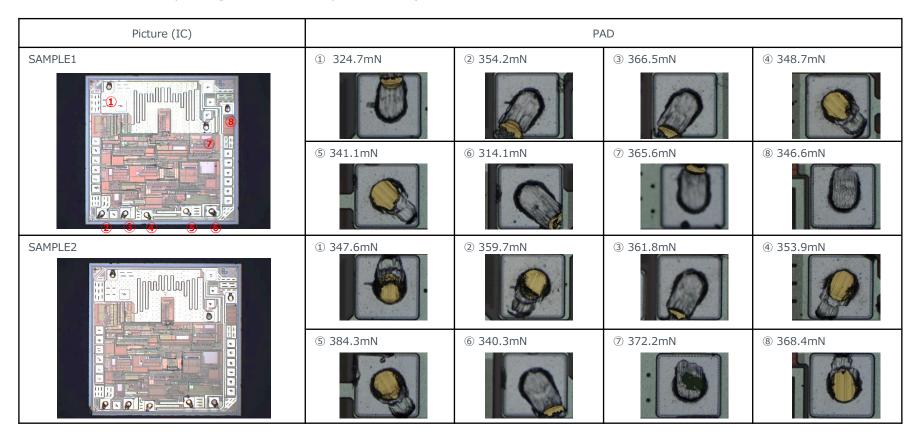
<HAST 192 h Analysis of good sample (2)>

HAST192h, WB share test is no problem.

■ Judgment standard : Above 200mN (Share strength), with Au remain or Al slide.

■ Number of samples : N=2pcs

■ Method : Mold opening \Rightarrow Microscope (×200)





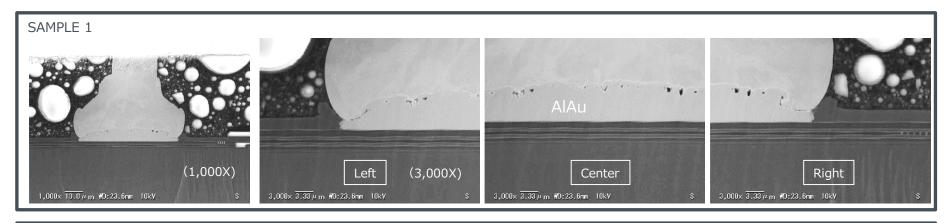
<HST 2000 h Analysis of good sample >

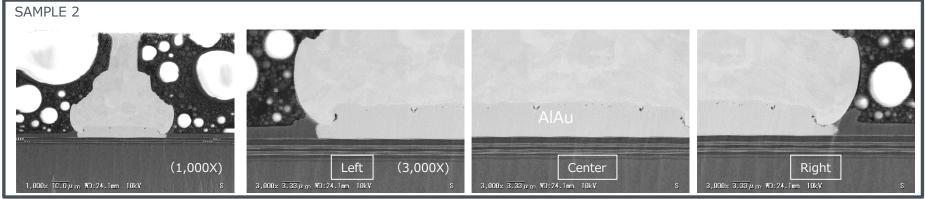
HST2000h, there are no crack by kirkendal void. There is no problem.

■ Judgment standard: No crack by kirkendal void

■ Number of samples : N=2pcs

■ Method : cross section polishing \Rightarrow SEM (×1000)





12. Summary



• To increase production capacity, add HTSOP-J8 high efficiency production line using higher number of products per frame.

•Based on DRBFM, check risk and list up process evaluation/Quality assurance test items. All results are no problem. Electrical characteristics is also no problem.



信頼性試験結果報告 Reliability Test Result

形状/PACKAGE:HTSOP-J8



2021年 7月 8日

LSI事業本部 LSI高品質設計部

LSI Business Unit,

LSI High Quality Design Division

矢野 茂秀 S.Yano

機種/TYPE :BDxxIC0MEFJ-M

【 信頼性試験結果 】

試験項目 ITEM	試験方法 METHOD	試験時間 DURATION	サンプル数 n (pcs)	不良数 pn (pcs)
半田耐熱性 <#2> Resistance to soldering heat	加湿処理後、赤外線リフロー加熱(ピーク260°C) After the moisture soaking treatment,carry	10s	22	0
	out the soldering heat stress(IR reflow :peak260°C) JEITA ED4701-301			
プレッシャークッカー〈#1〉 Pressure Cooker	121°C / 100% (2.026x10⁵Pa) に放置 Storage at 121°C/100% (2.026x10⁵Pa)	192h	22	0
温度サイクル〈#1〉 Temperature Cycling	Tstg min (30min) / Tstg max (30min) JEITA ED4701-105	500cycles	22	0
高温保存 High Temperature Storage	Tstg max に放置 Storage at Tstg max JEITA ED4701-201	2000h	22	0
低温保存 Low Temperature Storage	Tstg min に放置 Storage at Tstg min JEITA ED4701-202	2000h	22	0
高温高湿保存 <#1> Temperature Humidity Storage	85°C / 85% に放置 Place at 85°C/85% JEITA ED4701-103	2000h	22	0
高温高湿バイアス〈#1〉 Temperature Humidity Bias	85°C / 85% にて通電 JEITA ED4701-102 Apply the specified voltage at 85°C/85%	2000h	22	0
高温動作 High Temperature Operation Life	Topr max にて通電 JEITA ED4701-101 Apply the specified voltage at Topr max	2000h	22	0

【 強度試験結果 】

端子強度 (引っ張り)試験	Pull force = 1N	10s	5	0
Terminal strength	JEITA ED4701-401			
半田付け性試験	浸漬温度 215℃、鉛半田	10s	22	0
Solderability	Dipping temperature 215°C, (Pb) JEITA ED4701-303			
	浸漬温度 245℃、鉛フリー半田	5s	22	0
	Dipping temperature 245°C, (Pb free) JEITA ED4701-303			
静電破壊	C=100pF、R=1.5k Ω 、3times、 \pm 2000V	-	5	0
Electro Static Discharge	HBM (Human Body Model) JS-001 (JEITA ED4701-304)			
	C=200pF、R=0 Ω 、3times、 \pm 100V	_	5	0
	MM (Machine Model)			
	±750V	_	5	0
	CDM (Charged Device Model) JS-002			
ラッチアップ試験	パルス電流注入方法、トリガーパルス電流 ±100mA	_	5	0
Latch Up	Pulse current injection, trigger pulse current ±100mA JESD78 (JEITA ED4701-306)			

<<#1>> の試験項目につきましては、前処理として半田耐熱性試験を3回行った後に各試験を行います。 Soldering Heat examination is executed 3 times for the precondition.

<<#2>> 加湿処理 一般品 :85°C 85% 168h / 防湿梱包品 : 30°C 70% 192h Moisture soaking treatment Standard : 85°C 85% 168h / Dry packing : 30°C 70% 192h